# **SiT9386**

## AEC-Q100, 1 to 220 MHz Ultra-low Jitter Differential Oscillator



#### **Features**

- AEC-Q100 Grade 2 temperature range (-40°C to 105°C). Grade 3 and 4 also available
- Any frequency between 1 MHz and 220 MHz, accurate to 6 decimal places. For frequency between 220 and 725 MHz, see SiT9387
- LVPECL, LVDS and HCSL output signaling types
- 0.23 ps RMS (typ) phase jitter (random, 12 kHz to 20 MHz)
- Frequency stability as low as ±10 ppm contact SiTime
- Industry-standard packages: 3.2 x 2.5, 7.0 x 5.0 mm.
   Contact SiTime for 5.0 x 3.2 mm package

## **Applications**

- Automotive, and other high reliability electronics
- Infotainment systems, collision detection devices and in-vehicle 10/40/100 Gbps Ethernet









**Electrical Characteristics** 

## Table 1. Electrical Characteristics — Common to LVPECL, LVDS and HCSL

All Min and Max limits in the Electrical Characteristics tables are specified over temperature and rated operating voltage with standard output termination show in the termination diagrams. Typical values are at 25°C and nominal supply voltage.

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
			Free	quency Ran	ge		
Output Frequency Range	f	1	_	220	MHz	Accurate to 6 decimal places	
			Freq	uency Stab	ility		
Frequency Stability		-10	-	+10	ppm	Inclusive of initial tolerance, operating temperature, rated	
		-20	_	+20	ppm	power supply voltage and loadvariations.  Contact SiTime for ±10 ppm	
		-25	-	+25	ppm	Contact of time for £10 ppm	
		-50	-	+50	ppm		
First Year Aging	F_1y	-	±1	-	ppm	At 25°C	
			Tem	perature Ra	nge		
		-20	-	+70	°C	AEC-Q100 Grade 4	
Operating Temperature Range	T_use	-40	-	+85	°C	AEC-Q100 Grade 3	
		-40	-	+105	°C	AEC-Q100 Grade 2	
			Su	pply Voltag	е		
	Vdd	2.97	3.3	3.63	V		
Supply Voltage		2.70	3.0	3.30	V		
oupply voltage		2.52	2.8	3.08	V		
		2.25	2.5	2.75	V		
			Input	Characteris	stics		
Input Voltage High	VIH	70%	-	-	Vdd	Pin 1, OE	
Input Voltage Low	VIL	-	-	30%	Vdd	Pin 1, OE	
Input Pull-up Impedance	Z_in	-	100	-	kΩ	Pin 1, OE logic high or logic low	
	_		Outpu	ıt Character	istics		
Duty Cycle	DC	45	-	55	%		
	_		Startu	p and OE Ti	ming		
Start-up Time	T_start	-	-	3.0	ms	Measured from the time Vdd reaches its rated minimum value	
OE Enable/Disable Time	T_oe	_	_	3.8	μs		



Table 2. Electrical Characteristics - LVPECL

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
			Curre	nt Consump	tion	
Current Consumption	ldd	_	-	89	mA	Excluding Load Termination Current, Vdd = 3.3 V or 2.5 V
OE Disable Supply Current	I_OE	_	-	58	mA	OE = Low
Output Disable Leakage Current	l_leak	-	0.15	-	μА	OE = Low
Maximum Output Current	I_driver	_	-	33	mA	Maximum average current drawn from OUT+ or OUT-
			Output	t Characteri	stics	
Output High Voltage	VOH	Vdd-1.15	1	Vdd-0.7	V	See Figure 2
Output Low Voltage	VOL	Vdd-2.0	1	Vdd-1.5	V	See Figure 2
Output Differential Voltage Swing	V_Swing	1.2	1.6	2.0	V	See Figure 3
Rise/Fall Time	Tr, Tf	-	225	310	ps	20% to 80%, see Figure 3
			Jitter –	7.0 x 5.0 pag	ckage	
RMS Period Jitter <sup>[1]</sup>	T_jitt		1.0	1.6	ps	f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V
RMS Phase Jitter (random)	T_phj	-	0.225	0.270	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs.  Temperature ranges -20 to 70°C and -40 to 85°C
		-	0.225 0.300 ps f = 156.25 MHz, Integration bandwidth = 12 all Vdd levels, includes spurs.  Temperature range -40 to 105°C			
		-	0.1		ps	f = 156.25 or 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, includes spurs, all Vdd levels
			Jitter –	3.2 x 2.5 pa	ckage	
RMS Period Jitter[1]	T_jitt	_	1.0	1.6	ps	f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V
RMS Phase Jitter (random)	T_phj	ı	0.225	0.275	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs.  Temperature range -20 to 70°C and -40 to 85°C
		-	0.225	0.340	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs.  Temperature range -40 to 105°C
		-	0.1	_	ps	f = 156.25 or 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, includes spurs, all Vdd levels

## Notes:

<sup>1.</sup> Measured according to JESD65B.



Table 3. Electrical Characteristics - LVDS

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
			Curre	nt Consump	tion	
Current Consumption	ldd	1	ı	79	mA	Excluding Load Termination Current, Vdd = 3.3 V or 2.5 V
OE Disable Supply Current	I_OE	-	1	58	mA	OE = Low
Output Disable Leakage Current	I_leak	-	0.15	-	μΑ	OE = Low
Output Characteristics						
Differential Output Voltage	VOD	250	1	450	mV	See Figure 4
VOD Magnitude Change	ΔVOD	ı	ı	50	mV	See Figure 4
Offset Voltage	VOS	1.125	-	1.375	V	See Figure 4
VOS Magnitude Change	ΔVOS	_	-	50	mV	See Figure 4
Rise/Fall Time	Tr, Tf	ı	400	515	ps	Measured with 2 pF capacitive loading to GND, 20% to 80%, see Figure 5
			Jitter –	7.0 x 5.0 pa	ckage	
RMS Period Jitter <sup>[2]</sup>	T_jitt	İ	1.0	1.6	ps	f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V
RMS Phase Jitter (random)	T_phj	-	0.215	0.265	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs.  Temperature ranges -20 to 70°C and -40 to 85°C.
		-	0.215	0.300	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs.  Temperature range -40 to 105°C
		-	0.1	-	ps	f = 156.25 or 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, includes spurs, all Vdd levels.
			Jitter –	3.2 x 2.5 pa	ckage	
RMS Period Jitter <sup>[2]</sup>	T_jitt	-	1.0	1.6	ps	f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V
RMS Phase Jitter (random)	T_phj	ı	0.235	0.275	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs.  Temperature ranges -20 to 70°C and -40 to 85°C
		ı	0.235	0.320	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs.  Temperature range -40 to 105°C
		-	0.1	-	ps	f = 156.25 or 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, includes spurs, all Vdd levels

#### Notes:

2. Measured according to JESD65B.



Table 4. Electrical Characteristics - HCSL

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
			Curre	nt Consump	otion	
Current Consumption	ldd	_	-	92	mA	Excluding Load Termination Current, Vdd = 3.3 V or 2.5 V
OE Disable Supply Current	I_OE	-	-	58	mA	OE = Low
Output Disable Leakage Current	l_leak	ī	0.15	-	μΑ	OE = Low
Maximum Output Current	I_driver	ı	ı	35	mA	Maximum average current drawn from OUT+ or OUT-
			Outpu	t Characteri	stics	
Output High Voltage	VOH	0.60	-	0.90	V	See Figure 2
Output Low Voltage	VOL	-0.05	-	0.08	V	See Figure 2
Output Differential Voltage Swing	V_Swing	1.2	1.4	1.80	V	See Figure 3
Rise/Fall Time	Tr, Tf	ı	360	495	ps	Measured with 2 pF capacitive loading to GND, 20% to 80%, see Figure 3
			Jitter –	7.0 x 5.0 pa	ckage	
RMS Period Jitter <sup>[3]</sup>	T_jitt	Í	1.0	1.6	ps	f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V
RMS Phase Jitter (random)	T_phj	-	0.220	0.270	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs.  Temperature range -20 to 70°C and -40 to 85°C.
		-	0.220	0.300	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs.  Temperature range -40 to 105°C
		-	0.1	-	ps	f = 156.25 or 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, includes spurs, all Vdd levels.
			Jitter -	3.2 x 2.5 pa	ckage	
RMS Period Jitter[3]	T_jitt	-	1.0	1.6	ps	f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V
RMS Phase Jitter (random)	T_phj	ı	0.230	0.275	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs.  Temperature ranges -20 to 70°C and -40 to 85°C.
		ı	0.230	0.340	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs.  Temperature range -40 to 105°C
		-	0.1	-	ps	f = 156.25 or 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, includes spurs, all Vdd levels.

## Notes:

3. Measured according to JESD65B.



## **Table 5. Pin Description**

Pin	Мар	Functionality				
1	OE/NC  Output Enable (OE)  Non Connect (NC)		H <sup>[5]</sup> : specified frequency output L: output is high impedance			
'			H or L or Open: No effect on output frequency or other device functions			
2	NC	NA	No Connect; Leave it floating or connect to GND for better heat dissipation			
3	GND	Power	Vdd Power Supply Ground			
4	OUT+	Output	Oscillator output			
5	OUT-	Output Complementary oscillator output				
6 4	Vdd	Power				

# Top View OE/NC 1 6 VDD NC 2 5 OUT GND 3 4 OUT+

Figure 1. Pin Assignments

#### Notes:

- 5. In OE mode, a pull-up resistor of 10  $k\Omega$  or less is recommended if pin 1 is not externally driven.
- A capacitor of value 0.1 μF or higher between Vdd and GND is required. An additional 10 μF capacitor between Vdd and GND is required for the best phase jitter performance.

## **Table 6. Absolute Maximum Ratings**

Attempted operation outside the absolute maximum ratings may cause permanent damage to the part.

Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

Parameter	Min.	Max.	Unit
Vdd	-0.5	4.0	V
VIH		Vdd + 0.3V	V
VIL	-0.3		V
Storage Temperature	-65	150	°C
Maximum Junction Temperature		130	°C
Soldering Temperature (follow standard Pb-free soldering guidelines)		260	°C

## Table 7. Thermal Considerations[7]

Package	θ <sub>JA</sub> , 4 Layer Board (°C/W)	θ <sub>JC</sub> , Bottom (°C/W)
3225, 6-pin	80	30
7050, 6-pin	52	19

## Notes:

7. Refer to JESD51 for  $\theta_{JA}$  and  $\theta_{JC}$  definitions, and reference layout used to determine the  $\theta_{JA}$  and  $\theta_{JC}$  values in the above table.

## Table 8. Maximum Operating Junction Temperature<sup>[8]</sup>

Max Operating Temperature (ambient)	Maximum Operating Junction Temperature
70°C	95°C
85°C	110°C
105°C	130°C

#### Notes

8. Datasheet specifications are not guaranteed if junction temperature exceeds the maximum operating junction temperature.

## **Table 9. Environmental Compliance**

Parameter	Test Conditions	Value	Unit
Mechanical Shock Resistance	MIL-STD-883F, Method 2002	10,000	g
Mechanical Vibration Resistance	MIL-STD-883F, Method 2007	70	g
Soldering Temperature (follow standard Pb free soldering guidelines)	MIL-STD-883F, Method 2003	260	°C
Moisture Sensitivity Level	MSL1 @ 260°C		
Electrostatic Discharge (HBM)	HBM, JESD22-A114	2,000	V
Charge-Device Model ESD Protection	JESD220C101	750	V
Latch-up Tolerance	JESD'	78 Compliant	



# **Waveform Diagrams (continued)**

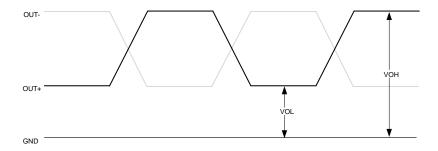


Figure 2. LVPECL/HCSL Voltage Levels per Differential Pin (OUT+/OUT-)

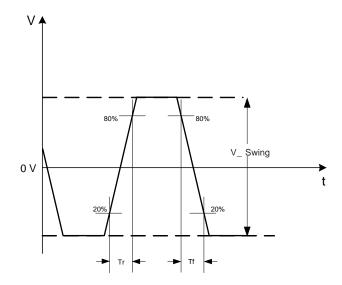


Figure 3. LVPECL/HCSL Voltage Levels across Differential Pair



# **Waveform Diagrams (continued)**

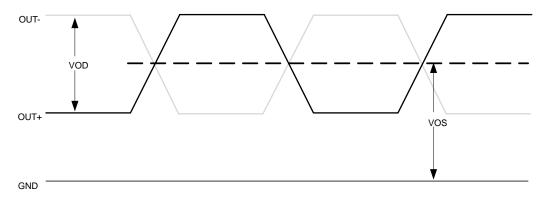


Figure 4. LVDS Voltage Levels per Differential Pin (OUT+/OUT-)

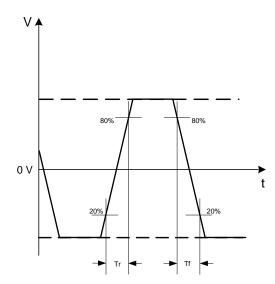


Figure 5. LVDS Differential Waveform

# **Timing Diagrams**

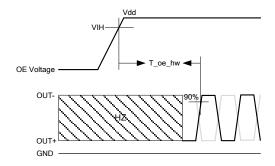


Figure 6. Hardware OE Enable Timing

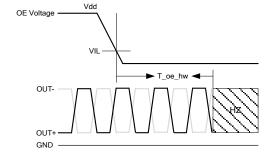


Figure 7. Hardware OE Disable Timing



# **Termination Diagrams**

## **LVPECL**

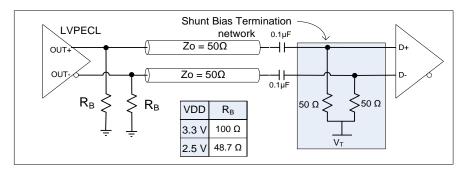


Figure 8. LVPECL with AC-coupled termination

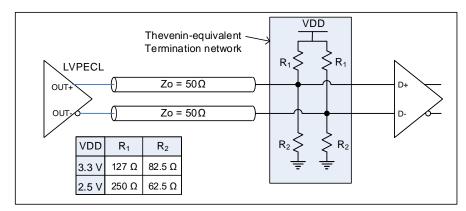


Figure 9. LVPECL DC-coupled load termination with Thevenin equivalent network

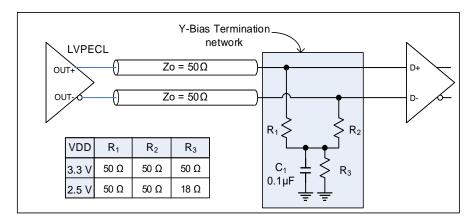


Figure 10. LVPECL with Y-Bias termination

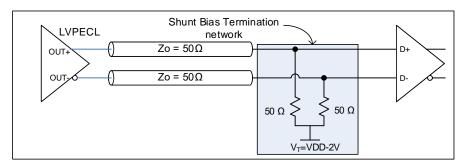


Figure 11. LVPECL with DC-coupled parallel shunt load termination



## **Termination Diagrams (continued)**

## **LVDS**

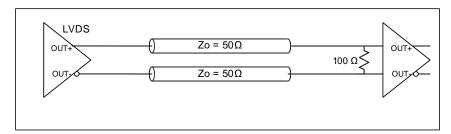


Figure 12. LVDS single DC termination at the load

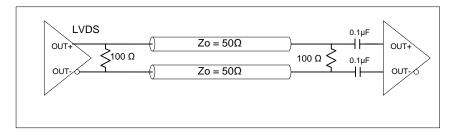


Figure 13. LVDS double AC termination with capacitor close to the load

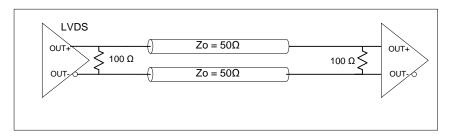


Figure 14. LVDS double DC termination

## **HCSL**

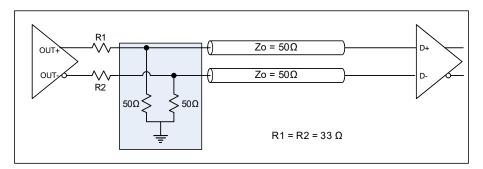
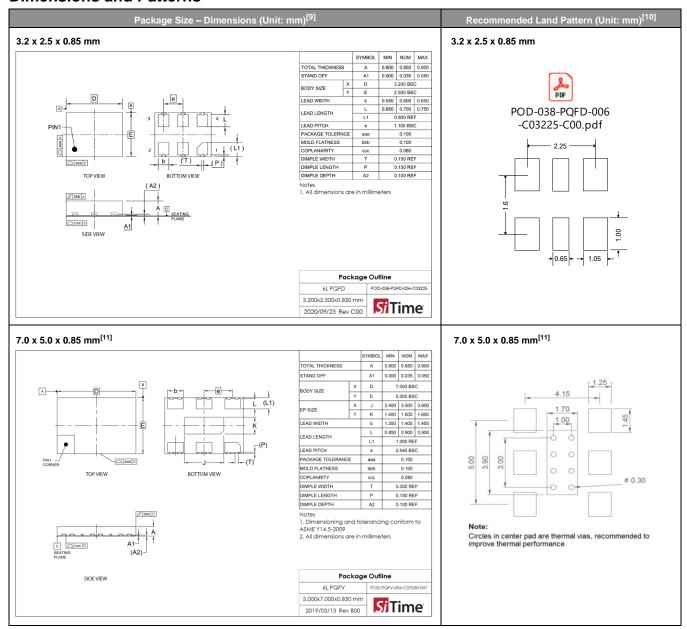


Figure 15. HCSL interface termination



## **Dimensions and Patterns**

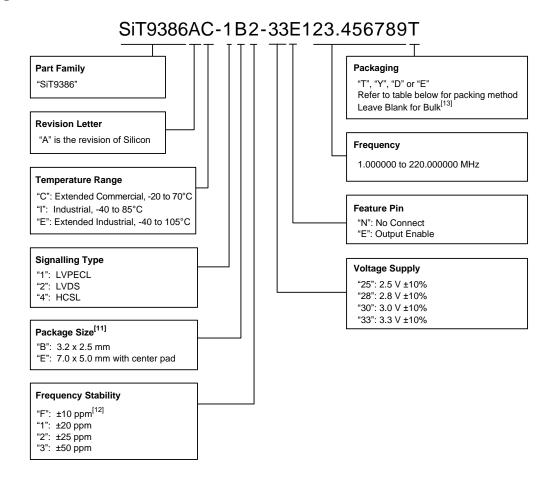


#### Notes:

- 9. Top Marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
- 10. A capacitor of value 0.1 μF or higher between Vdd and GND is required. An additional 10 μF capacitor between Vdd and GND is required for the best phase jitter performance
- 11. The center pad has no electrical function. Soldering down the center pad to the GND is recommended for best thermal dissipation, but is optional.



# **Ordering Information**



#### Notes:

- 12. Contact SiTime for 5.0 x 3.2 mm package.
- 13. Contact SiTime for ±10 ppm option.
- 14. Bulk is available for sampling only.

Table 10. Ordering Codes for Supported Tape & Reel Packing Method

Device Size (mm x mm)	8 mm T&R (3ku)	8 mm T&R (1ku)	12 mm T&R (3ku)	12 mm T&R (1ku)	16 mm T&R (3ku)	16 mm T&R (1ku)
7.0 x 5.0	_	_	_	_	Т	Y
3.2 x 2.5	D	Е			_	_



## **Table 11. Additional Information**

Document	Description	Download Link
ECCN #: EAR99	Five character designation used on the commerce Control List (CCL) to identify dual use items for export control purposes.	
Part number Generator	Tool used to create the part number based on desired features.	https://www.sitime.com/part-number-generator
Manufacturing Notes	Tape & Reel dimension, reflow profile and other manufacturing related info	https://www.sitime.com/sites/default/files/gated/Manufacturing-Notes-for-SiTime-Products.pdf
Qualification Reports	RoHS report, reliability reports, composition reports	http://www.sitime.com/support/quality-and-reliability
Performance Reports	Additional performance data such as phase noise, current consumption and jitter for selected frequencies	http://www.sitime.com/support/performance-measurement-report
Termination Techniques	Termination design recommendations	http://www.sitime.com/support/application-notes
Layout Techniques	Layout recommendations	http://www.sitime.com/support/application-notes

## **Table 12. Revision History**

Revision	Release Date	Change Summary
0.1	8-Mar-2021	Initial draft
0.87	6-Nov-2017	Updated package drawings Corrected tape/reel ordering information Updated Electrical Characteristics based on characterization Included max numbers for IPJ Added additional information table Corrected formatting issues Increased temperature range from 95°C to 105°C Removed ±10 ppm options for automotive and industrial temperature ranges Changed ±20 ppm to "contact SiTime" Updated termination diagrams Lower mechanical shock from 20,000 to 10,000 g
0.90	24-Nov-2017	Ordering information updates and page layout changes
1.0	15-Mar-2019	Updated Electrical Characteristics tables Updated waveform diagrams Added OE enable/disable timing diagrams Updated package dimensions Added an AEC-Q100 Grade 4 temperature option Updated the ordering information
1.01	9-Mar-2021	Updated L1 and Dimple Width package dimensions for 3.2 x 2.5 mm package Updated hyperlinks and changed rev table date format

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